

RN2412TE85LF Information


For Reference Only

Part Number RN2412TE85LF
Manufacturer Toshiba Semiconductor and Storage
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Single, Pre-Biased
Description TRANS PREBIAS PNP 0.2W SMINI
Package TO-236-3, SC-59, SOT-23-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


RN2412TE85LF Specifications

Manufacturer Part Number	RN2412TE85LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	PNP - Pre-Biased
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	22k
Resistor - Emitter Base (R2) (Ohms)	-
DC Current Gain (hFE) (Min) @ Ic, Vce	120 @ 1mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA
Current - Collector Cutoff (Max)	100nA (ICBO)
Frequency - Transition	200MHz
Power - Max	200mW
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	S-Mini

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RN2412TE85LF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RN2412TE85LF Payment Methods



RN2412TE85LF Shipping Methods



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